

- 1N821-1, 1N823-1, 1N825-1, 1N827-1 AND 1N829-1 AVAILABLE IN JAN, JANTX, JANTXV AND JANS PER MIL-PRF-19500/159
- TEMPERATURE COMPENSATED ZENER REFERENCE DIODES
- METALLURGICALLY BONDED
- DOUBLE PLUG CONSTRUCTION

1N821 thru 1N829A  
and  
1N821-1 thru 1N829-1

## MAXIMUM RATINGS

Operating Temperature: -65°C to +175°C  
Storage Temperature: -65°C to +175°C  
DC Power Dissipation: 500mW @ +50°C  
Power Derating: 4 mW / °C above +50°C

## REVERSE LEAKAGE CURRENT

$I_R = 2\mu A$  @ 25°C &  $V_R = 3$  Vdc

ELECTRICAL CHARACTERISTICS @ 25°C, unless otherwise specified.

| JEDEC<br>TYPE<br>NUMBER    | ZENER<br>VOLTAGE<br>$V_Z$ @ $I_{ZT}$ | ZENER<br>TEST<br>CURRENT<br>$I_{ZT}$ | MAXIMUM<br>ZENER<br>IMPEDANCE<br>(Note 1)<br>$Z_{ZT}$ | VOLTAGE<br>TEMPERATURE<br>STABILITY<br>$\Delta V_{ZT}$<br>-55° to +100°<br>(Note 2) | EFFECTIVE<br>TEMPERATURE<br>COEFFICIENT |
|----------------------------|--------------------------------------|--------------------------------------|-------------------------------------------------------|-------------------------------------------------------------------------------------|-----------------------------------------|
|                            | VOLTS                                | mA                                   | OHMS                                                  | mV                                                                                  | % / °C                                  |
| 1N821<br>1N821A<br>1N822 † | 5.9—6.5<br>5.9—6.5<br>5.9—6.5        | 7.5<br>7.5<br>7.5                    | 15<br>10<br>15                                        | 96<br>96<br>96                                                                      | 0.01<br>0.01<br>0.01                    |
| 1N823<br>1N823A<br>1N824 † | 5.9—6.5<br>5.9—6.5<br>5.9—6.5        | 7.5<br>7.5<br>7.5                    | 15<br>10<br>15                                        | 48<br>48<br>48                                                                      | 0.005<br>0.005<br>0.005                 |
| 1N825<br>1N825A<br>1N826   | 5.9—6.5<br>5.9—6.5<br>6.2—6.9        | 7.5<br>7.5<br>7.5                    | 15<br>10<br>15                                        | 19<br>19<br>20                                                                      | 0.002<br>0.002<br>0.002                 |
| 1N827<br>1N827A<br>1N828   | 5.9—6.5<br>5.9—6.5<br>6.2—6.9        | 7.5<br>7.5<br>7.5                    | 15<br>10<br>15                                        | 9<br>9<br>10                                                                        | 0.001<br>0.001<br>0.001                 |
| 1N829<br>1N829A            | 5.9—6.5<br>5.9—6.5                   | 7.5<br>7.5                           | 15<br>10                                              | 5<br>5                                                                              | 0.0005<br>0.0005                        |

† Double Anode: Electrical Specifications Apply Under Both Bias Polarities.

**NOTE 1** Zener impedance is derived by superimposing on  $I_{ZT}$  A 60Hz rms a.c. current equal to 10% of  $I_{ZT}$ .

**NOTE 2** The maximum allowable change observed over the entire temperature range i.e., the diode voltage will not exceed the specified mV at any discrete temperature between the established limits, per JEDEC standard No. 5.

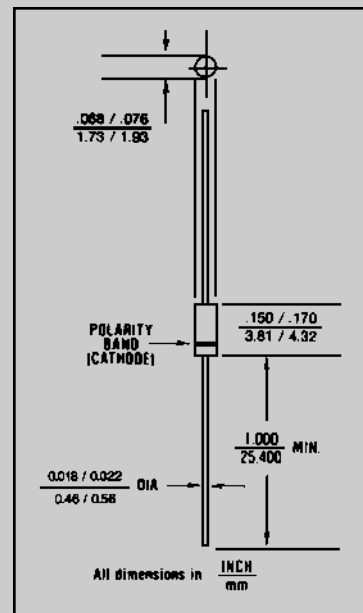


FIGURE 1

## DESIGN DATA

**CASE:** Hermetically sealed glass case. DO – 35 outline.

**LEAD MATERIAL:** Copper clad steel.

**LEAD FINISH:** Tin / Lead

**POLARITY:** Diode to be operated with the banded (cathode) end positive.

**MOUNTING POSITION:** Any.

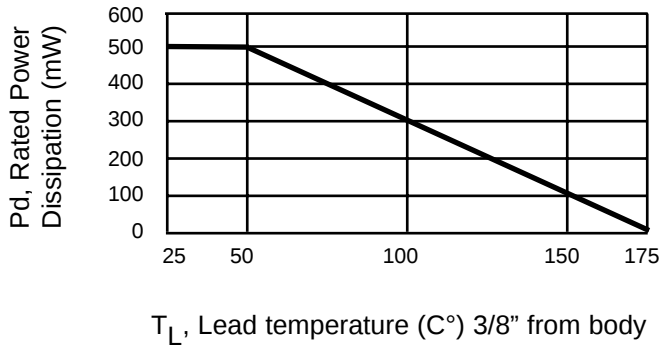


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PHONE (978) 620-2600  
WEBSITE: <http://www.microsemi.com>

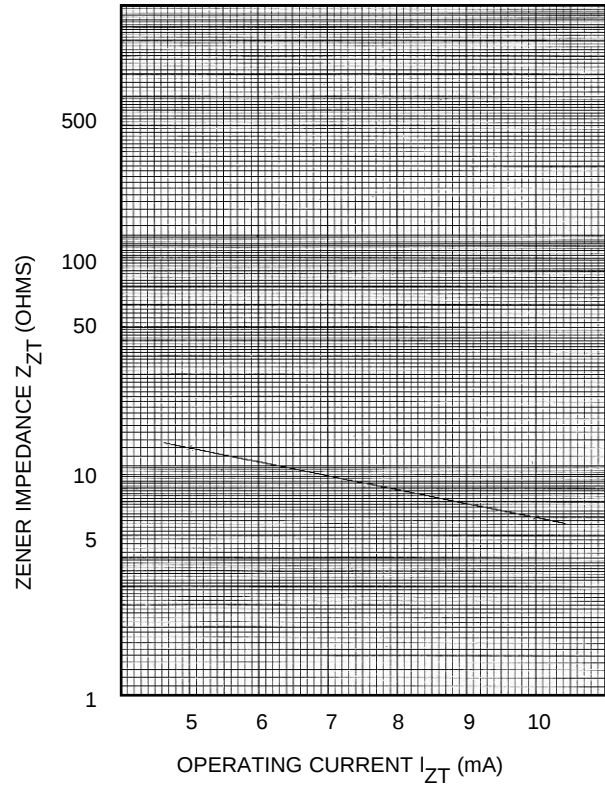
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# 1N821 thru 1N829A

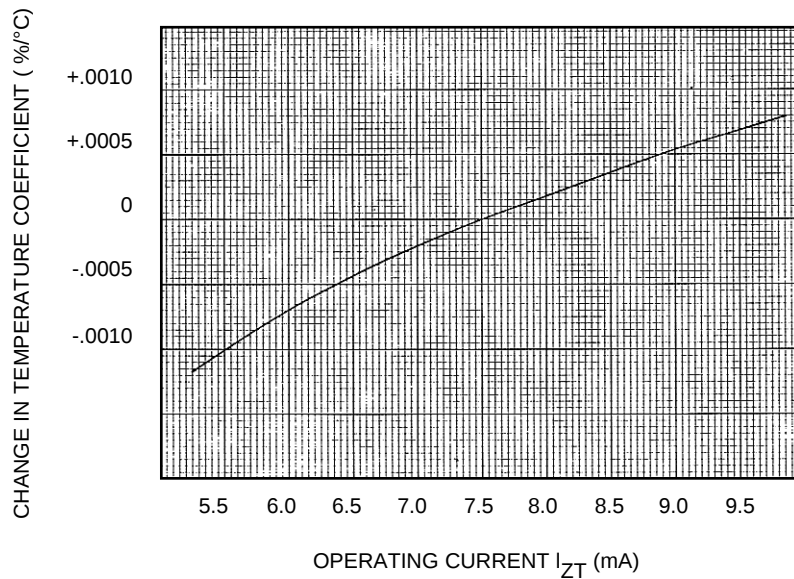
## INCLUDING -1 VERSIONS



**FIGURE 2**  
**POWER DERATING CURVE**



**FIGURE 3**  
**ZENER IMPEDANCE**  
**VS.**  
**OPERATING CURRENT**



**FIGURE 4**  
**TYPICAL CHANGE OF TEMPERATURE**  
**COEFFICIENT WITH CHANGE IN**  
**OPERATING CURRENT**